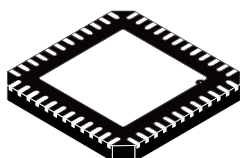


## DMOS dual full bridge driver

Datasheet - production data



VFQFPN48  
(7 x 7 mm)

### Description

The L6207Q device is a DMOS dual full bridge driver designed for motor control applications, realized in BCDmultipower technology, which combines isolated DMOS power transistors with CMOS and bipolar circuits on the same chip. The device also includes two independent constant OFF time PWM current controllers that perform the chopping regulation. Available in a VFQFPN48 7 x 7 package, the L6207Q device features thermal shutdown and a non-dissipative overcurrent detection on the high-side Power MOSFETs.

### Features

- Operating supply voltage from 8 to 52 V
- 5.6 A output peak current
- $R_{DS(on)}$  0.3  $\Omega$  typ. value at  $T_j = 25^\circ\text{C}$
- Operating frequency up to 100 kHz
- Non-dissipative overcurrent protection
- Dual independent constant  $t_{OFF}$  PWM current controllers
- Slow decay synchronous rectification
- Cross conduction protection
- Thermal shutdown
- Undervoltage lockout
- Integrated fast freewheeling diodes

### Applications

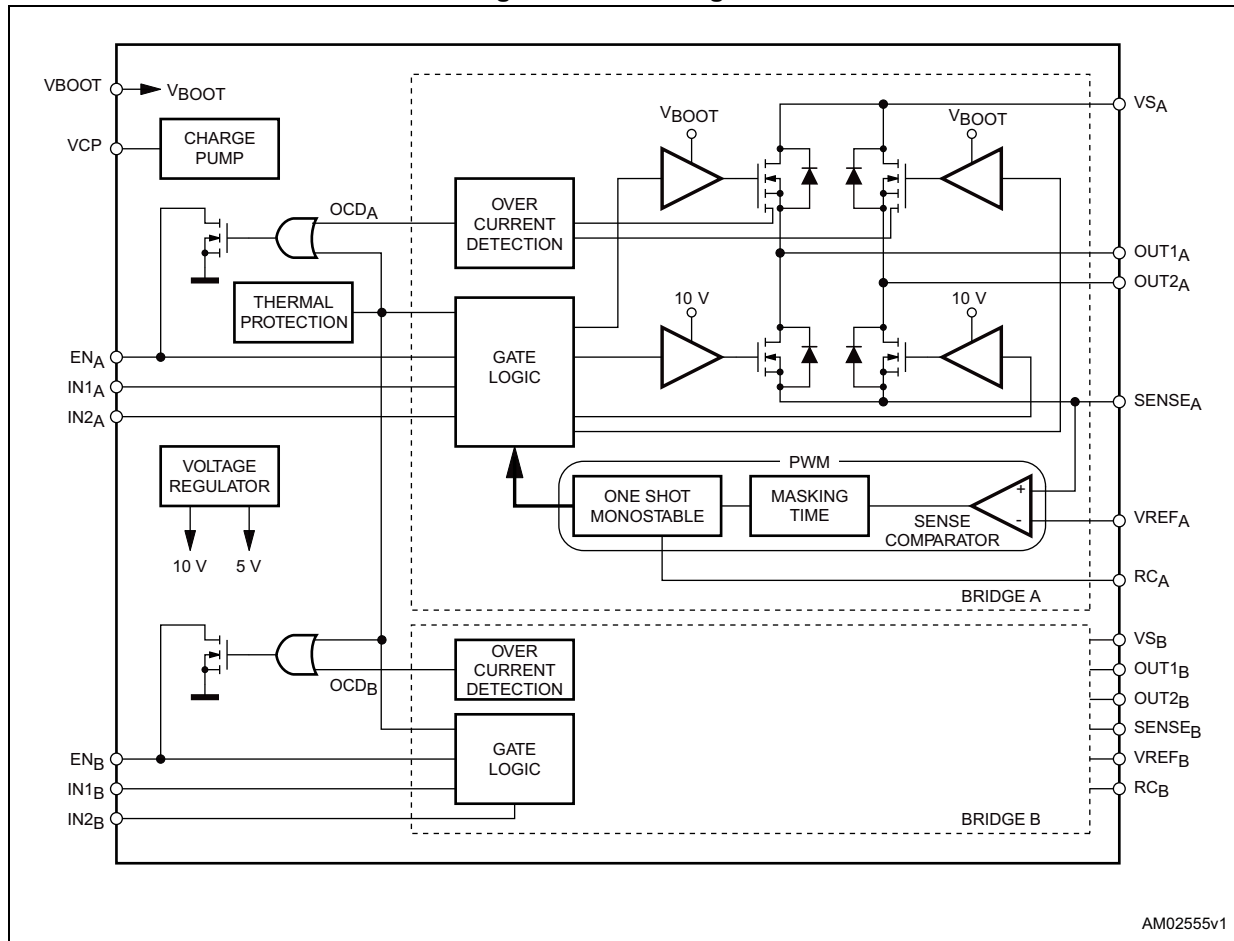
- Bipolar stepper motor
- Dual or quad DC motor

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# 1 Block diagram

Figure 1. Block diagram



## 2 Electrical data

### 2.1 Absolute maximum ratings

Table 1. Absolute maximum ratings

| Symbol                           | Parameter                                                                                                              | Test condition                                                                      | Value      | Unit |
|----------------------------------|------------------------------------------------------------------------------------------------------------------------|-------------------------------------------------------------------------------------|------------|------|
| $V_S$                            | Supply voltage                                                                                                         | $V_{SA} = V_{SB} = V_S$                                                             | 60         | V    |
| $V_{OD}$                         | Differential voltage between $V_{SA}$ , $OUT1_A$ , $OUT2_A$ , $SENSE_A$ and $V_{SB}$ , $OUT1_B$ , $OUT2_B$ , $SENSE_B$ | $V_{SA} = V_{SB} = V_S = 60\text{ V}$ ;<br>$V_{SENSE_A} = V_{SENSE_B} = \text{GND}$ | 60         | V    |
| $V_{BOOT}$                       | Bootstrap peak voltage                                                                                                 | $V_{SA} = V_{SB} = V_S$                                                             | $V_S + 10$ | V    |
| $V_{IN}, V_{EN}$                 | Input and enable voltage range                                                                                         |                                                                                     | -0.3 to +7 | V    |
| $V_{REFA}$ ,<br>$V_{REFB}$       | Voltage range at pins $V_{REFA}$ and $V_{REFB}$                                                                        |                                                                                     | -0.3 to +7 | V    |
| $V_{RCA}, V_{RCB}$               | Voltage range at pins $RC_A$ and $RC_B$                                                                                |                                                                                     | -0.3 to +7 | V    |
| $V_{SENSE_A}$ ,<br>$V_{SENSE_B}$ | Voltage range at pins $SENSE_A$ and $SENSE_B$                                                                          |                                                                                     | -1 to +4   | V    |
| $I_{S(\text{peak})}$             | Pulsed supply current (for each $V_S$ pin), internally limited by the overcurrent protection                           | $V_{SA} = V_{SB} = V_S$ ;<br>$t_{PULSE} < 1\text{ ms}$                              | 7.1        | A    |
| $I_S$                            | RMS supply current (for each $V_S$ pin)                                                                                | $V_{SA} = V_{SB} = V_S$                                                             | 2.5        | A    |
| $T_{stg}, T_{OP}$                | Storage and operating temperature range                                                                                |                                                                                     | -40 to 150 | °C   |

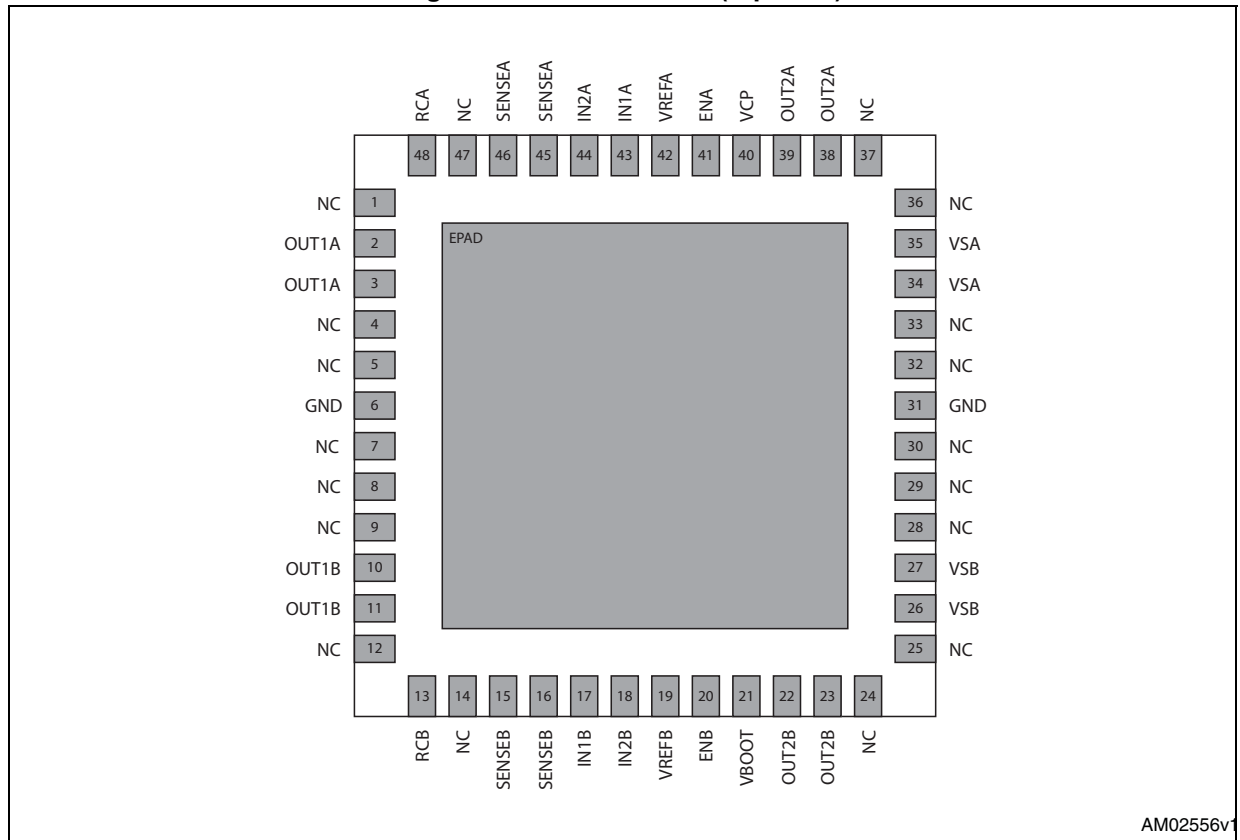
### 2.2 Recommended operating conditions

Table 2. Recommended operating conditions

| Symbol                           | Parameter                                                                                                              | Test condition                                           | Min. | Max. | Unit |
|----------------------------------|------------------------------------------------------------------------------------------------------------------------|----------------------------------------------------------|------|------|------|
| $V_S$                            | Supply voltage                                                                                                         | $V_{SA} = V_{SB} = V_S$                                  | 8    | 52   | V    |
| $V_{OD}$                         | Differential voltage between $V_{SA}$ , $OUT1_A$ , $OUT2_A$ , $SENSE_A$ and $V_{SB}$ , $OUT1_B$ , $OUT2_B$ , $SENSE_B$ | $V_{SA} = V_{SB} = V_S$ ;<br>$V_{SENSE_A} = V_{SENSE_B}$ |      | 52   | V    |
| $V_{SENSE_A}$ ,<br>$V_{SENSE_B}$ | Voltage range at pins $SENSE_A$ and $SENSE_B$                                                                          | Pulsed $t_W < t_{rr}$                                    | -6   | 6    | V    |
|                                  |                                                                                                                        | DC                                                       | -1   | 1    | V    |
| $I_{OUT}$                        | RMS output current                                                                                                     |                                                          |      | 2.5  | A    |
| $T_j$                            | Operating junction temperature                                                                                         |                                                          | -25  | +125 | °C   |
| $f_{sw}$                         | Switching frequency                                                                                                    |                                                          |      | 100  | kHz  |

### 3 Pin connection

Figure 2. Pin connection (top view)



Note: The exposed PAD must be connected to GND pin.

Table 3. Pin description

| Pin    | Name   | Type         | Function                                                                                                                      |
|--------|--------|--------------|-------------------------------------------------------------------------------------------------------------------------------|
| 43     | IN1A   | Logic input  | Bridge A logic input 1.                                                                                                       |
| 44     | IN2A   | Logic input  | Bridge A logic input 2.                                                                                                       |
| 45, 46 | SENSEA | Power supply | Bridge A source pin. This pin must be connected to power ground through a sensing power resistor.                             |
| 48     | RCA    | RC pin       | RC network pin. A parallel RC network connected between this pin and ground sets the current controller OFF time of bridge A. |
| 2, 3   | OUT1A  | Power output | Bridge A output 1.                                                                                                            |
| 6, 31  | GND    | GND          | Signal ground terminals. These pins are also used for heat dissipation toward the PCB.                                        |
| 10, 11 | OUT1B  | Power output | Bridge B output 1.                                                                                                            |
| 13     | RCB    | RC pin       | RC network pin. A parallel RC network connected between this pin and ground sets the current controller OFF time of bridge B. |

Table 3. Pin description (continued)

| Pin    | Name   | Type                       | Function                                                                                                                                                                                                                                                                         |
|--------|--------|----------------------------|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 15, 16 | SENSEB | Power supply               | Bridge B source pin. This pin must be connected to power ground through a sensing power resistor.                                                                                                                                                                                |
| 17     | IN1B   | Logic input                | Bridge B input 1                                                                                                                                                                                                                                                                 |
| 18     | IN2B   | Logic input                | Bridge B input 2                                                                                                                                                                                                                                                                 |
| 19     | VREFB  | Analog input               | Bridge B current controller reference voltage. Do not leave this pin open or connect to GND.                                                                                                                                                                                     |
| 20     | ENB    | Logic input <sup>(1)</sup> | Bridge B enable. Low logic level switches off all power MOSFETs of Bridge B. This pin is also connected to the collector of the overcurrent and thermal protection transistor to implement overcurrent protection. If not used, it must be connected to +5 V through a resistor. |
| 21     | VBOOT  | Supply voltage             | Bootstrap voltage needed for driving the upper power MOSFETs of both Bridge A and bridge B.                                                                                                                                                                                      |
| 22, 23 | OUT2B  | Power output               | Bridge B output 2.                                                                                                                                                                                                                                                               |
| 26, 27 | VSB    | Power supply               | Bridge B power supply voltage. It must be connected to the supply voltage together with pin VSA.                                                                                                                                                                                 |
| 34, 35 | VSA    | Power supply               | Bridge A power supply voltage. It must be connected to the supply voltage together with pin VSB.                                                                                                                                                                                 |
| 38, 39 | OUT2A  | Power output               | Bridge A output 2.                                                                                                                                                                                                                                                               |
| 40     | VCP    | Output                     | Charge pump oscillator output.                                                                                                                                                                                                                                                   |
| 41     | ENA    | Logic input <sup>(1)</sup> | Bridge A enable. Low logic level switches off all power MOSFETs of bridge A. This pin is also connected to the collector of the overcurrent and transistor to implement overcurrent protection. If not used, it must be connected to +5 V through a resistor. Thermal protection |
| 42     | VREFA  | Analog input               | Bridge A current controller reference voltage. Do not leave this pin open or connect to GND.                                                                                                                                                                                     |

1. Also connected at the output drain of the overcurrent and thermal protection MOSFET. Therefore, it must be driven putting in series a resistor with a value in the range of 2.2 k $\Omega$  - 180 k $\Omega$ , recommended 100 k $\Omega$ .

## 4 Electrical characteristics

$V_S = 48\text{ V}$ ,  $T_A = 25\text{ °C}$ , unless otherwise specified.

**Table 4. Electrical characteristics**

| Symbol                    | Parameter                                        | Test condition                                                    | Min.  | Typ. | Max. | Unit |
|---------------------------|--------------------------------------------------|-------------------------------------------------------------------|-------|------|------|------|
| V <sub>Sth(ON)</sub>      | Turn-on threshold                                |                                                                   | 6.6   | 7    | 7.4  | V    |
| V <sub>Sth(OFF)</sub>     | Turn-off threshold                               |                                                                   | 5.6   | 6    | 6.4  | V    |
| I <sub>S</sub>            | Quiescent supply current                         | All bridges OFF; T <sub>J</sub> = -25 °C to 125 °C <sup>(1)</sup> |       | 5    | 10   | mA   |
| T <sub>J(OFF)</sub>       | Thermal shutdown temperature                     |                                                                   |       | 165  |      | °C   |
| Output DMOS transistors   |                                                  |                                                                   |       |      |      |      |
| R <sub>DS(ON)</sub>       | High-side switch ON resistance                   | T <sub>J</sub> = 25 °C                                            |       | 0.34 | 0.4  | Ω    |
|                           |                                                  | T <sub>J</sub> = 125 °C <sup>(1)</sup>                            |       | 0.53 | 0.59 |      |
|                           | Low-side switch ON resistance                    | T <sub>J</sub> = 25 °C                                            |       | 0.28 | 0.34 |      |
|                           |                                                  | T <sub>J</sub> = 125 °C <sup>(1)</sup>                            |       | 0.47 | 0.53 |      |
| I <sub>DSS</sub>          | Leakage current                                  | EN = low; OUT = V <sub>S</sub>                                    |       |      | 2    | mA   |
|                           |                                                  | EN = low; OUT = GND                                               | -0.15 |      |      | mA   |
| Source drain diodes       |                                                  |                                                                   |       |      |      |      |
| V <sub>SD</sub>           | Forward ON voltage                               | I <sub>SD</sub> = 2.5 A, EN = low                                 |       | 1.15 | 1.3  | V    |
| t <sub>rr</sub>           | Reverse recovery time                            | I <sub>f</sub> = 2.5 A                                            |       | 300  |      | ns   |
| t <sub>fr</sub>           | Forward recovery time                            |                                                                   |       | 200  |      | ns   |
| Logic input               |                                                  |                                                                   |       |      |      |      |
| V <sub>IL</sub>           | Low level logic input voltage                    |                                                                   | -0.3  |      | 0.8  | V    |
| V <sub>IH</sub>           | High level logic input voltage                   |                                                                   | 2     |      | 7    | V    |
| I <sub>IL</sub>           | Low level logic input current                    | GND logic input voltage                                           | -10   |      |      | μA   |
| I <sub>IH</sub>           | High level logic input current                   | 7 V logic input voltage                                           |       |      | 10   | μA   |
| V <sub>th(ON)</sub>       | Turn-on input threshold                          |                                                                   |       | 1.8  | 2    | V    |
| V <sub>th(OFF)</sub>      | Turn-off input threshold                         |                                                                   | 0.8   | 1.3  |      | V    |
| V <sub>th(HYS)</sub>      | Input threshold hysteresis                       |                                                                   | 0.25  | 0.5  |      | V    |
| Switching characteristics |                                                  |                                                                   |       |      |      |      |
| t <sub>D(on)EN</sub>      | Enable to out turn ON delay time <sup>(2)</sup>  | I <sub>LOAD</sub> = 2.5 A, resistive load                         | 100   | 250  | 400  | ns   |
| t <sub>D(on)IN</sub>      | Input to out turn ON delay time                  | I <sub>LOAD</sub> = 2.5 A, resistive load (deadtime included)     |       | 1.6  |      | μs   |
| t <sub>RISE</sub>         | Output rise time <sup>(2)</sup>                  | I <sub>LOAD</sub> = 2.5 A, resistive load                         | 40    |      | 250  | ns   |
| t <sub>D(off)EN</sub>     | Enable to out turn OFF delay time <sup>(2)</sup> | I <sub>LOAD</sub> = 2.5 A, resistive load                         | 300   | 550  | 800  | ns   |
| t <sub>D(off)IN</sub>     | Input to out turn OFF delay time                 | I <sub>LOAD</sub> = 2.5 A, resistive load                         |       | 600  |      | ns   |

Table 4. Electrical characteristics (continued)

| Symbol                               | Parameter                                                          | Test condition                                                           | Min. | Typ.    | Max. | Unit          |
|--------------------------------------|--------------------------------------------------------------------|--------------------------------------------------------------------------|------|---------|------|---------------|
| $t_{\text{FALL}}$                    | Output fall time <sup>(2)</sup>                                    | $I_{\text{LOAD}} = 2.5 \text{ A}$ , resistive load                       | 40   |         | 250  | ns            |
| $t_{\text{DT}}$                      | Deadtime protection                                                |                                                                          | 0.5  | 1       |      | $\mu\text{s}$ |
| $f_{\text{CP}}$                      | Charge pump frequency                                              | $-25\text{ }^{\circ}\text{C} < T_j < 125\text{ }^{\circ}\text{C}$        |      | 0.6     | 1    | MHz           |
| <b>PWM comparator and monostable</b> |                                                                    |                                                                          |      |         |      |               |
| $I_{\text{RCA}}, I_{\text{RCB}}$     | Source current at pins RCA and RCB                                 | $V_{\text{RCA}} = V_{\text{RCB}} = 2.5 \text{ V}$                        | 3.5  | 5.5     |      | mA            |
| $V_{\text{offset}}$                  | Offset voltage on sense comparator                                 | $V_{\text{REFA}}, V_{\text{REFB}} = 0.5 \text{ V}$                       |      | $\pm 5$ |      | mV            |
| $t_{\text{PROP}}$                    | Turn OFF propagation delay <sup>(3)</sup>                          |                                                                          |      | 500     |      | ns            |
| $t_{\text{BLANK}}$                   | Internal blanking time on SENSE pins                               |                                                                          |      | 1       |      | $\mu\text{s}$ |
| $t_{\text{ON(MIN)}}$                 | Minimum ON time                                                    |                                                                          |      | 1.5     | 2    | $\mu\text{s}$ |
| $t_{\text{OFF}}$                     | PWM recirculation time                                             | $R_{\text{OFF}} = 20 \text{ k}\Omega$ ; $C_{\text{OFF}} = 1 \text{ nF}$  |      | 13      |      | $\mu\text{s}$ |
|                                      |                                                                    | $R_{\text{OFF}} = 100 \text{ k}\Omega$ ; $C_{\text{OFF}} = 1 \text{ nF}$ |      | 61      |      | $\mu\text{s}$ |
| $I_{\text{BIAS}}$                    | Input bias current at pins $V_{\text{REFA}}$ and $V_{\text{REFB}}$ |                                                                          |      |         | 10   | $\mu\text{A}$ |
| <b>Over current detection</b>        |                                                                    |                                                                          |      |         |      |               |
| $I_{\text{sover}}$                   | Input supply overcurrent detection threshold                       | $-25\text{ }^{\circ}\text{C} < T_j < 125\text{ }^{\circ}\text{C}$        | 4    | 5.6     | 7.1  | A             |
| $R_{\text{OPDR}}$                    | Open drain ON resistance                                           | $I = 4 \text{ mA}$                                                       |      | 40      | 60   | $\Omega$      |
| $t_{\text{OCD(ON)}}$                 | OCD turn-on delay time <sup>(4)</sup>                              | $I = 4 \text{ mA}$ ; $C_{\text{EN}} < 100 \text{ pF}$                    |      | 200     |      | ns            |
| $t_{\text{OCD(OFF)}}$                | OCD turn-off delay time <sup>(4)</sup>                             | $I = 4 \text{ mA}$ ; $C_{\text{EN}} < 100 \text{ pF}$                    |      | 100     |      | ns            |

1. Tested at 25 °C in a restricted range and guaranteed by characterization.

2. See [Figure 3](#).

3. Measured applying a voltage of 1 V to pin SENSE and a voltage drop from 2 V to 0 V to pin  $V_{\text{REF}}$ .

4. See [Figure 4](#).



Figure 3. Switching characteristic definition

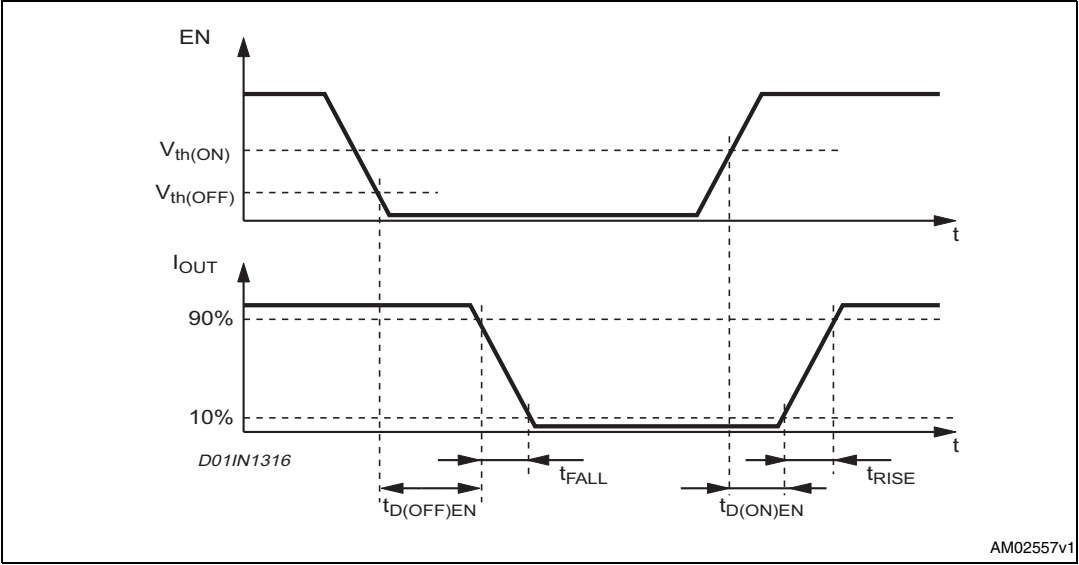
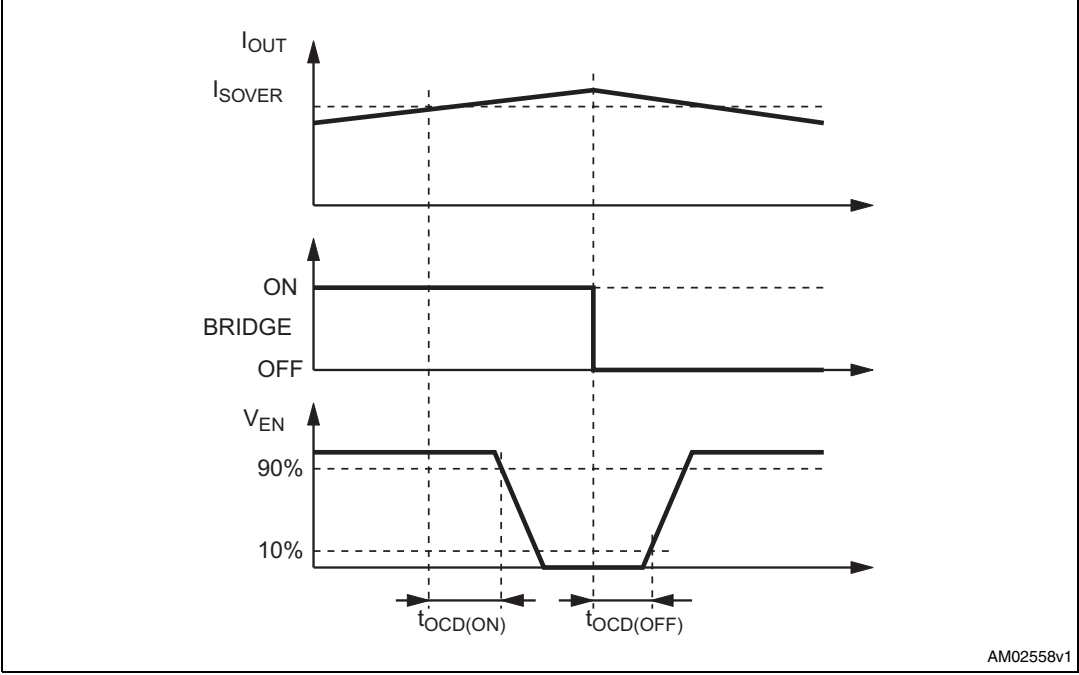


Figure 4. Overcurrent detection timing definition



# 5 Circuit description

## 5.1 Power stages and charge pump

The L6207Q device integrates two independent power MOSFET full bridges, each power MOSFET has an  $R_{DS(ON)} = 0.3 \Omega$  (typical value at 25 °C) with intrinsic fast freewheeling diode. Cross conduction protection is implemented by using a deadtime ( $t_{DT} = 1 \mu s$  typical value) set by internal timing circuit between the turn-off and turn-on of two power MOSFETs in one leg of a bridge.

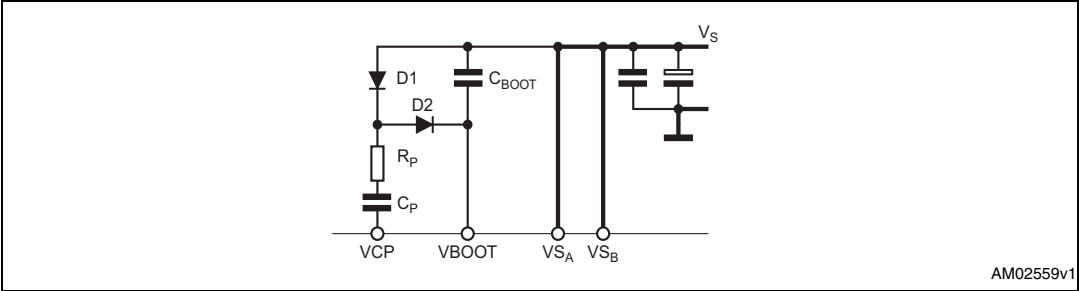
Pins  $VS_A$  and  $VS_B$  must be connected together to the supply voltage ( $V_S$ ).

Using an N-channel power MOSFET for the upper transistors in the bridge requires a gate drive voltage above the power supply voltage. The bootstrapped supply ( $V_{BOOT}$ ) is obtained through an internal oscillator and a few external components to realize a charge pump circuit, as shown in [Figure 5](#). The oscillator output (pin VCP) is a square wave at 600 kHz (typically) with 10 V amplitude. Recommended values/part numbers for the charge pump circuit are shown in [Table 5](#).

Table 5. Charge pump external component values

| Component  | Value        |
|------------|--------------|
| $C_{BOOT}$ | 220 nF       |
| $C_P$      | 10 nF        |
| $R_P$      | 100 $\Omega$ |
| D1         | 1N4148       |
| D2         | 1N4148       |

Figure 5. Charge pump circuit

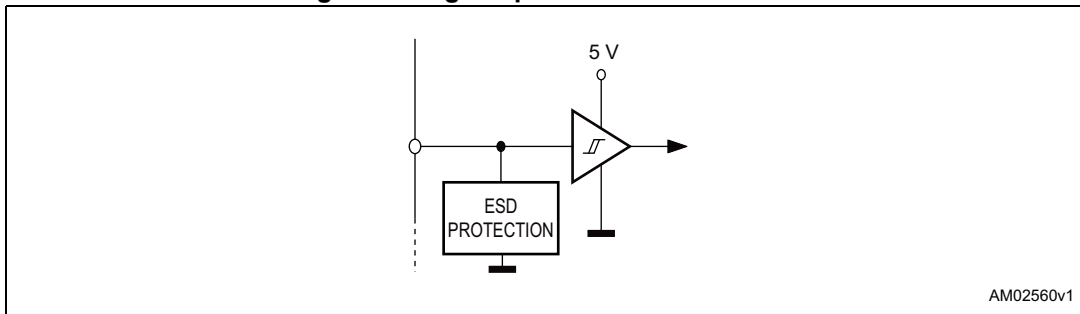


## 5.2 Logic inputs

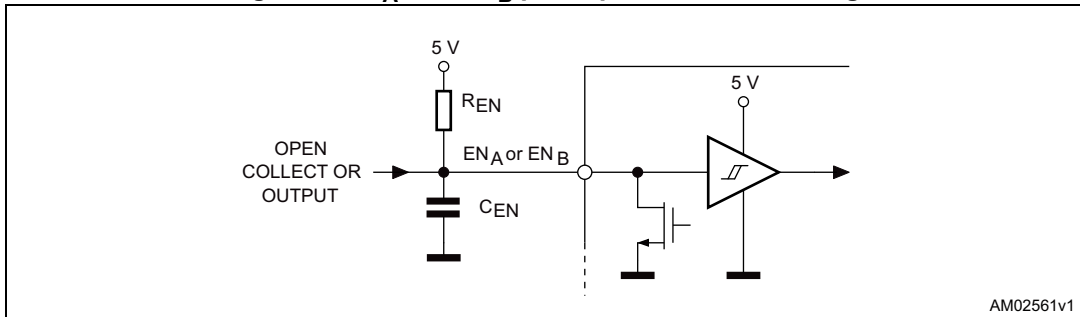
Pins IN1<sub>A</sub>, IN2<sub>A</sub>, IN1<sub>B</sub> and IN2<sub>B</sub> are TTL/CMOS and  $\mu$ C compatible logic inputs. The internal structure is shown in [Figure 6](#). Typical values for turn-on and turn-off thresholds are respectively  $V_{th(ON)} = 1.8$  V and  $V_{th(OFF)} = 1.3$  V.

Pins EN<sub>A</sub> and EN<sub>B</sub> have identical input structures with the exception that the drains of the overcurrent and thermal protection MOSFETs (one for bridge A and one for bridge B) are also connected to these pins. Due to these connections, some care must be taken in driving these pins. Two configurations are shown in [Figure 7](#) and [8](#). If driven by an open drain (collector) structure, a pull-up resistor  $R_{EN}$  and a capacitor  $C_{EN}$  are connected, as shown in [Figure 7](#). If the driver is a standard push-pull structure, the resistor  $R_{EN}$  and the capacitor  $C_{EN}$  are connected, as shown in [Figure 8](#). The resistor  $R_{EN}$  should be chosen in the range from 2.2 k $\Omega$  to 180 k $\Omega$ . Recommended values for  $R_{EN}$  and  $C_{EN}$  are respectively 100 k $\Omega$  and 5.6 nF. More information on selecting the values is found in [Section 5.5](#).

**Figure 6. Logic inputs internal structure**



**Figure 7. EN<sub>A</sub> and EN<sub>B</sub> pins open collector driving**



**Figure 8. EN<sub>A</sub> and EN<sub>B</sub> pins push-pull driving**

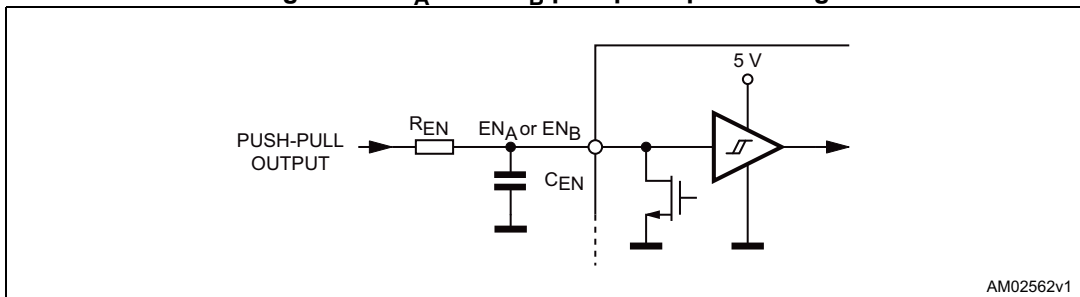


Table 6. Truth table

| Inputs |                  |     | Outputs               |                                      | Description <sup>(1)</sup> |
|--------|------------------|-----|-----------------------|--------------------------------------|----------------------------|
| EN     | IN1              | IN2 | OUT1                  | OUT2                                 |                            |
| L      | X <sup>(2)</sup> | X   | High Z <sup>(3)</sup> | High Z                               | Disable                    |
| H      | L                | L   | GND                   | GND                                  | Brake mode (lower path)    |
| H      | H                | L   | V <sub>S</sub>        | GND (V <sub>S</sub> ) <sup>(4)</sup> | Forward                    |
| H      | L                | H   | GND (V <sub>S</sub> ) | V <sub>S</sub>                       | Reverse                    |
| H      | H                | H   | V <sub>S</sub>        | V <sub>S</sub>                       | Brake mode (upper path)    |

1. Valid only in case of load connected between OUT1 and OUT2.

2. X = don't care.

3. High Z = high impedance output.

4. GND (V<sub>S</sub>) = GND during t<sub>ON</sub>, V<sub>S</sub> during t<sub>OFF</sub>.

### 5.3 PWM current control

The L6207Q device includes a constant OFF time PWM current controller for each of the two bridges. The current control circuit senses the bridge current by sensing the voltage drop across an external sense resistor connected between the source of the two lower power MOSFET transistors and ground, as shown in [Figure 9](#). As the current in the load builds up, the voltage across the sense resistor increases proportionally. When the voltage drop across the sense resistor becomes greater than the voltage at the reference input (VREF<sub>A</sub> or VREF<sub>B</sub>), the sense comparator triggers the monostable switching the low-side MOSFET off. The low-side MOSFET remains off for the time set by the monostable and the motor current recirculates in the upper path. When the monostable times out, the bridge again turns on. As the internal deadtime, used to prevent cross conduction in the bridge, delays the turn-on of the power MOSFET, the effective OFF time is the sum of the monostable time plus the deadtime.

Figure 9. PWM current controller simplified schematic

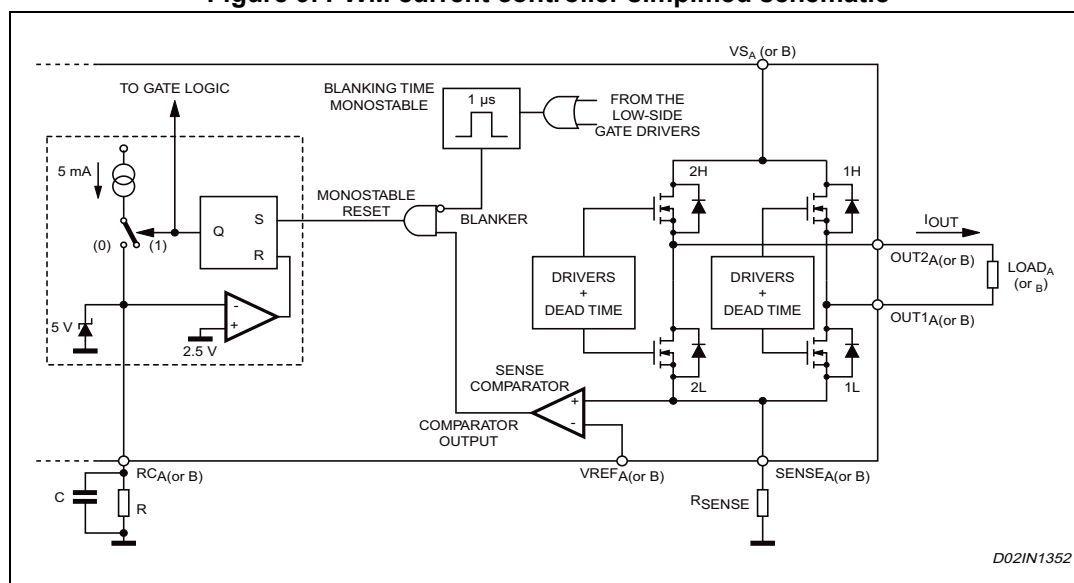
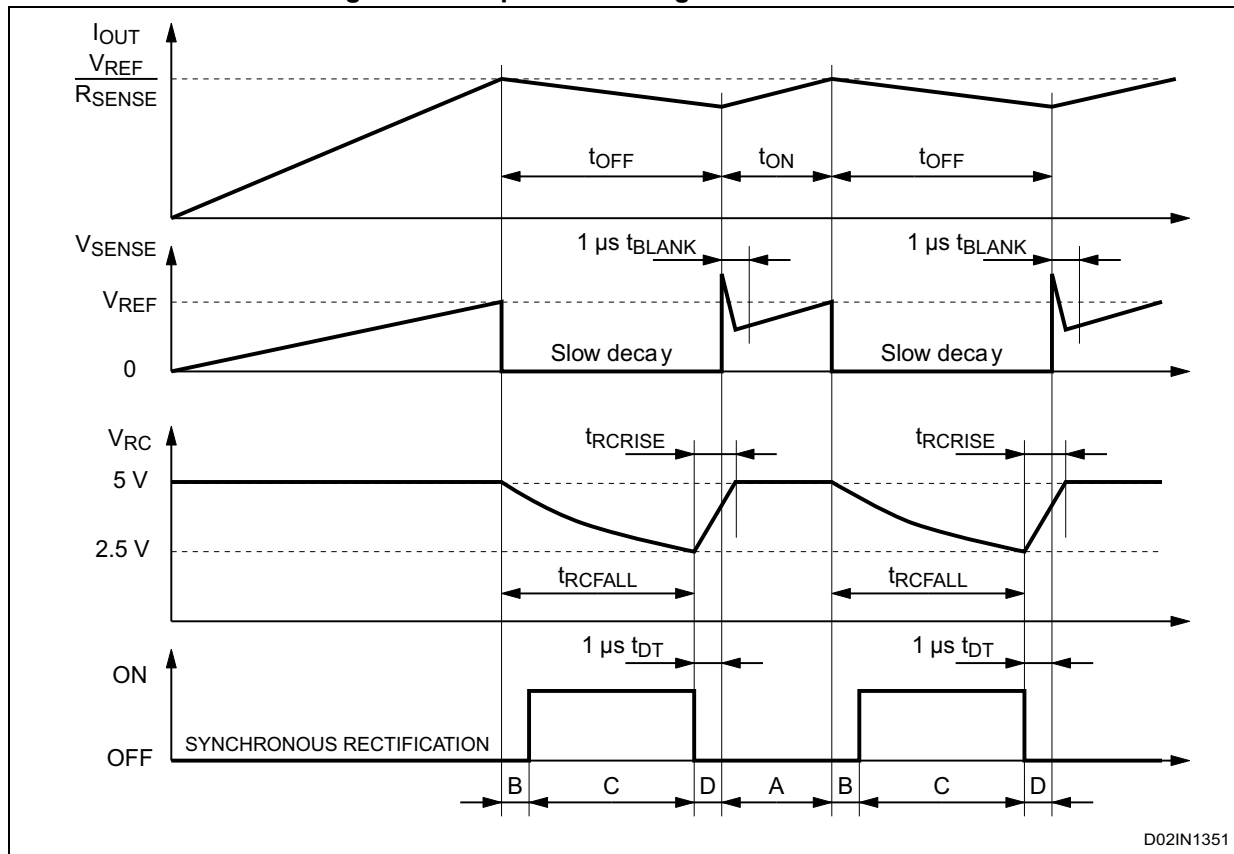


Figure 10 shows the typical operating waveforms of the output current, the voltage drop across the sensing resistor, the RC pin voltage and the status of the bridge. Immediately after the low-side Power MOSFET turns on, a high peak current flows through the sensing resistor due to the reverse recovery of the freewheeling diodes. The L6207Q device provides a  $1\text{ }\mu\text{s}$  blanking time  $t_{\text{BLANK}}$  that inhibits the comparator output so that this current spike cannot prematurely retrigger the monostable.

Figure 10. Output current regulation waveforms



*Figure 11* shows the magnitude of the OFF time  $t_{\text{OFF}}$  versus  $C_{\text{OFF}}$  and  $R_{\text{OFF}}$  values. It can be approximately calculated from *Equation 1* and *Equation 2*:

**Equation 1**

$$t_{\text{RCFALL}} = 0.6 \cdot R_{\text{OFF}} \cdot C_{\text{OFF}}$$

**Equation 2**

$$t_{\text{OFF}} = t_{\text{RCFALL}} + t_{\text{DT}} = 0.6 \cdot R_{\text{OFF}} \cdot C_{\text{OFF}} + t_{\text{DT}}$$

where  $R_{\text{OFF}}$  and  $C_{\text{OFF}}$  are the external component values and  $t_{\text{DT}}$  is the internally generated deadtime with:

**Equation 3**

$$20 \text{ k}\Omega \leq R_{\text{OFF}} \leq 100 \text{ k}\Omega$$

$$0.47 \text{ nF} \leq C_{\text{OFF}} \leq 100 \text{ nF}$$

$$t_{\text{DT}} = 1 \text{ }\mu\text{s (typical value)}$$

therefore:

**Equation 4**

$$t_{\text{OFF(MIN)}} = 6.6 \text{ }\mu\text{s}$$

$$t_{\text{OFF(MAX)}} = 6 \text{ ms}$$

These values allow a sufficient range of  $t_{\text{OFF}}$  to implement the drive circuit for most motors.

The capacitor value chosen for  $C_{\text{OFF}}$  also affects the rise time  $t_{\text{RCRISE}}$  of the voltage at the pin  $R_{\text{COFF}}$ . The rise time  $t_{\text{RCRISE}}$  is only an issue if the capacitor is not completely charged before the next time the monostable is triggered. Therefore, the ON time  $t_{\text{ON}}$ , which depends on motors and supply parameters, must be bigger than  $t_{\text{RCRISE}}$  to allow a good current regulation by the PWM stage. Furthermore, the ON time  $t_{\text{ON}}$  can not be smaller than the minimum ON time  $t_{\text{ON(MIN)}}$ .

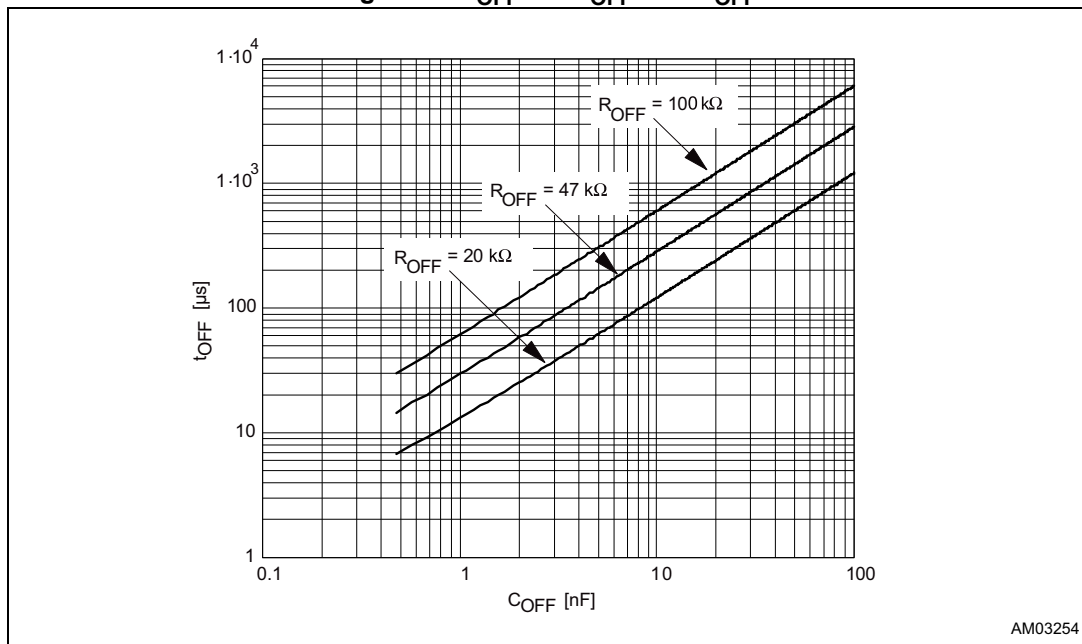
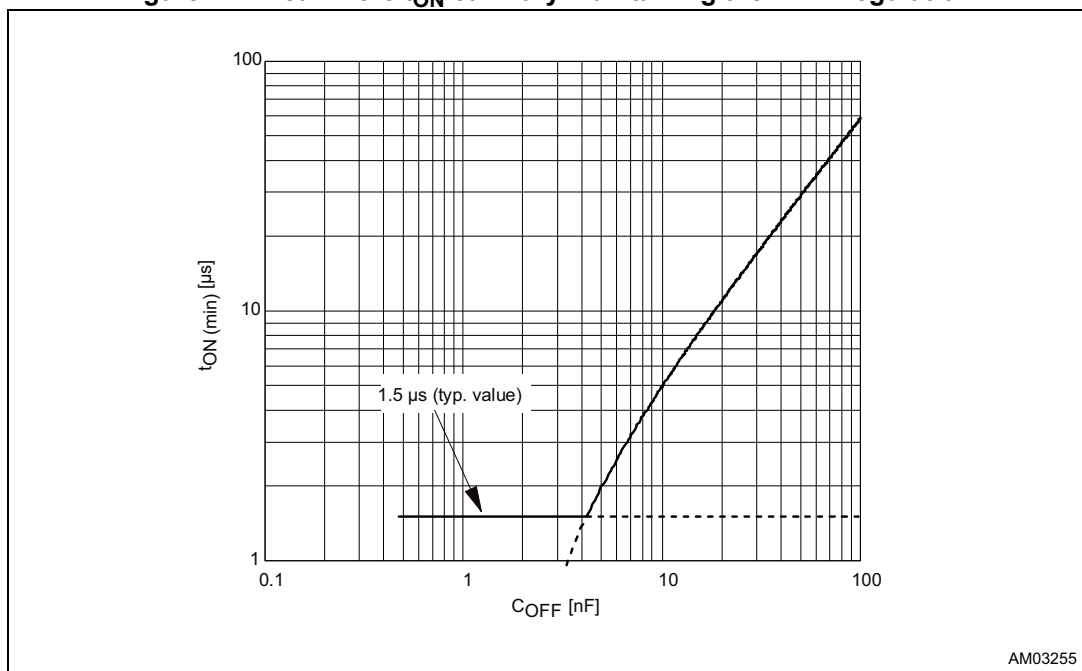
**Equation 5**

$$\left\{ \begin{array}{l} t_{\text{ON}} > t_{\text{ON(MIN)}} \\ t_{\text{ON}} > t_{\text{RCRISE}} - t_{\text{DT}} \end{array} \right. = 1,5\mu\text{s(typ)}$$

$$t_{\text{RCRISE}} = 600 \cdot C_{\text{OFF}}$$

*Figure 12* shows the lower limit for the ON time  $t_{\text{ON}}$  for having a good PWM current regulation capacity. It should be mentioned that  $t_{\text{ON}}$  is always bigger than  $t_{\text{ON(MIN)}}$  because the device imposes this condition, but it can be smaller than  $t_{\text{RCRISE}} - t_{\text{DT}}$ . In this last case the device continues to work but the OFF time  $t_{\text{OFF}}$  is not more constant.

Therefore, a small  $C_{\text{OFF}}$  value gives more flexibility to the applications (allows smaller ON time and, therefore, higher switching frequency), but, the smaller the value for  $C_{\text{OFF}}$ , the more influential the noises on the circuit performance.

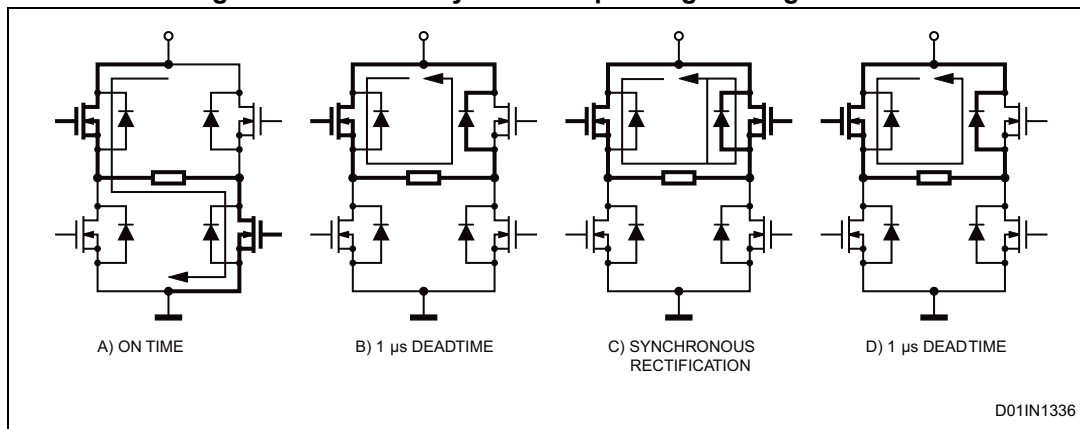
Figure 11.  $t_{OFF}$  vs.  $C_{OFF}$  and  $R_{OFF}$ Figure 12. Area where  $t_{ON}$  can vary maintaining the PWM regulation

## 5.4 Slow decay mode

Figure 13 shows the operation of the bridge in slow decay mode. At the start of the OFF time, the lower power MOSFET is switched off and the current recirculates around the upper half of the bridge. Since the voltage across the coil is low, the current decays slowly. After the deadtime the upper power MOSFET is operated in the synchronous rectification mode.

When the monostable times out, the lower power MOSFET is turned on again after some delay set by the deadtime to prevent cross conduction.

**Figure 13. Slow decay mode output stage configurations**



## 5.5 Non-dissipative overcurrent detection and protection

The L6207Q device integrates an overcurrent detection circuit (OCD).

With this internal overcurrent detection, the external current sense resistor normally used and its associated power dissipation are eliminated. [Figure 14](#) shows a simplified schematic of the overcurrent detection circuit for bridge A. Bridge B is provided by an analogous circuit.

To implement the overcurrent detection, a sensing element that delivers a small but precise fraction of the output current is implemented with each high-side power MOSFET. Since this current is a small fraction of the output current there is very little additional power dissipation. This current is compared with an internal reference current  $I_{REF}$ . When the output current reaches the detection threshold (typically 5.6 A) the OCD comparator signals a fault condition. When a fault condition is detected, an internal open drain MOSFET with a pull-down capability of 4 mA connected to the EN pin is turned on. [Figure 15](#) shows the OCD operation.

By using an external R-C on the EN pin, as shown in [Figure 14](#), the OFF time before recovering normal operation can be easily programmed by means of the accurate thresholds of the logic inputs.

The disable time  $t_{DISABLE}$  before recovering normal operation can be easily programmed by means of the accurate thresholds of the logic inputs. It is affected by both  $C_{EN}$  and  $R_{EN}$  values and its magnitude is reported in [Figure 16](#). The delay time  $t_{DELAY}$  before turning off the bridge when an overcurrent has been detected depends only on the  $C_{EN}$  value. Its magnitude is reported in [Figure 17](#).

$C_{EN}$  is also used for providing immunity to pin EN against fast transient noises. Therefore the value of  $C_{EN}$  should be chosen as big as possible according to the maximum tolerable delay time and the  $R_{EN}$  value should be chosen according to the desired disable time.

The resistor  $R_{EN}$  should be chosen in the range from 2.2 k $\Omega$  to 180 k $\Omega$ . Recommended values for  $R_{EN}$  and  $C_{EN}$  are respectively 100 k $\Omega$  and 5.6 nF which allow to obtain 200  $\mu$ s disable time.



Figure 14. Overcurrent protection simplified schematic

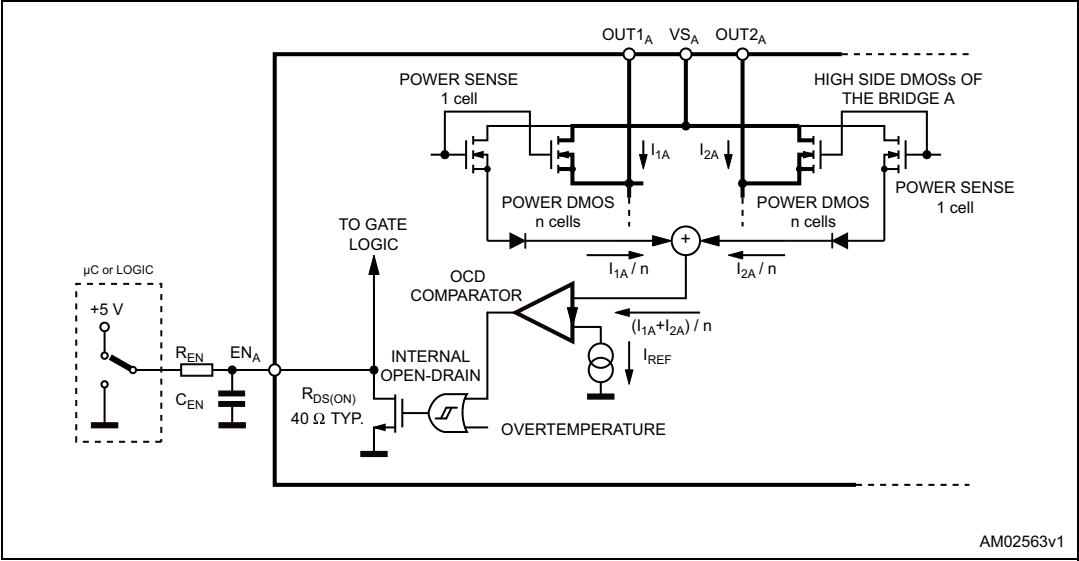


Figure 15. Overcurrent protection waveforms

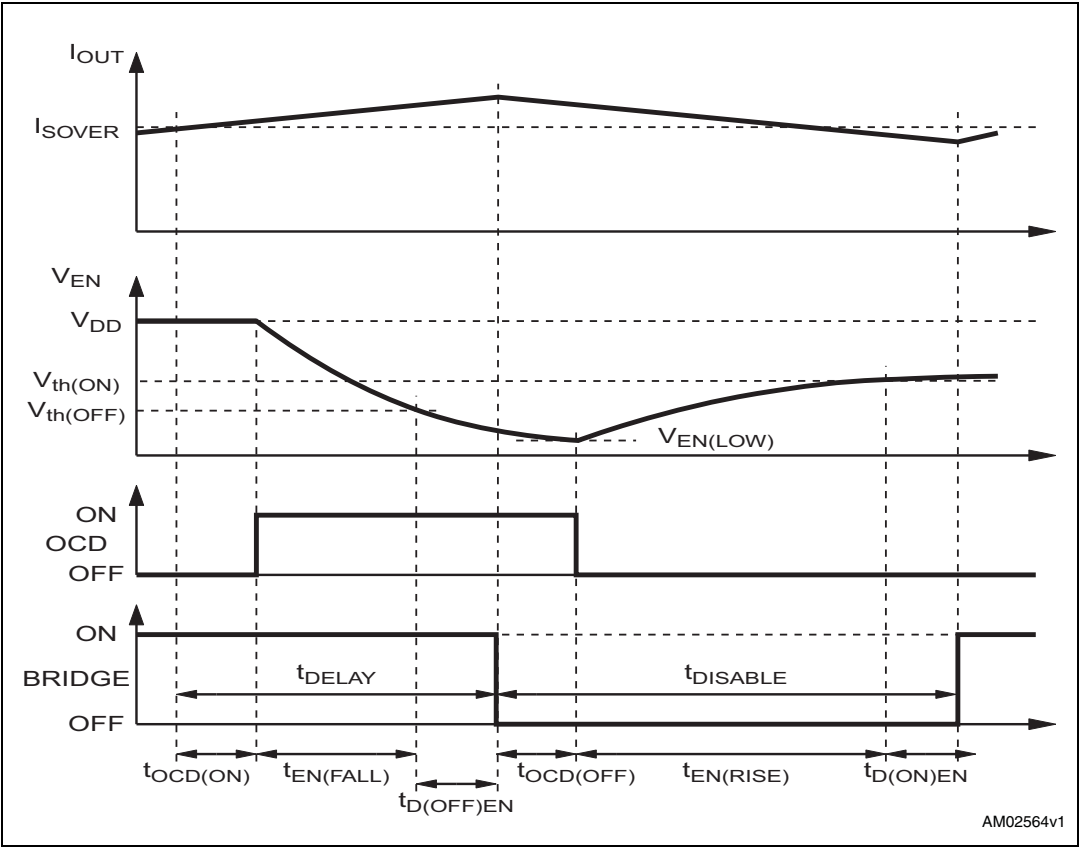
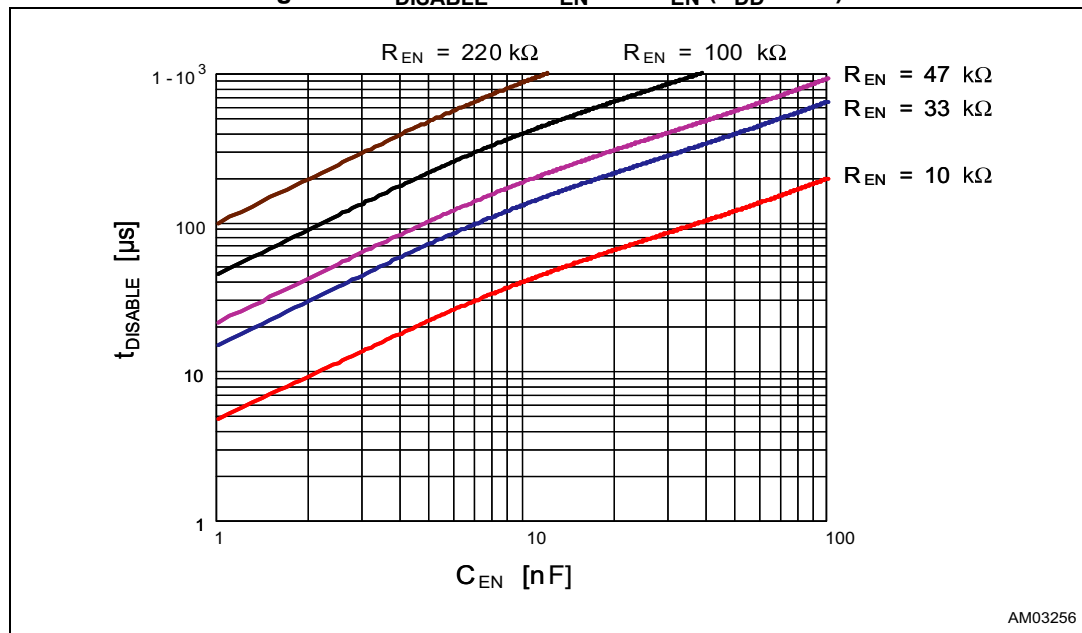
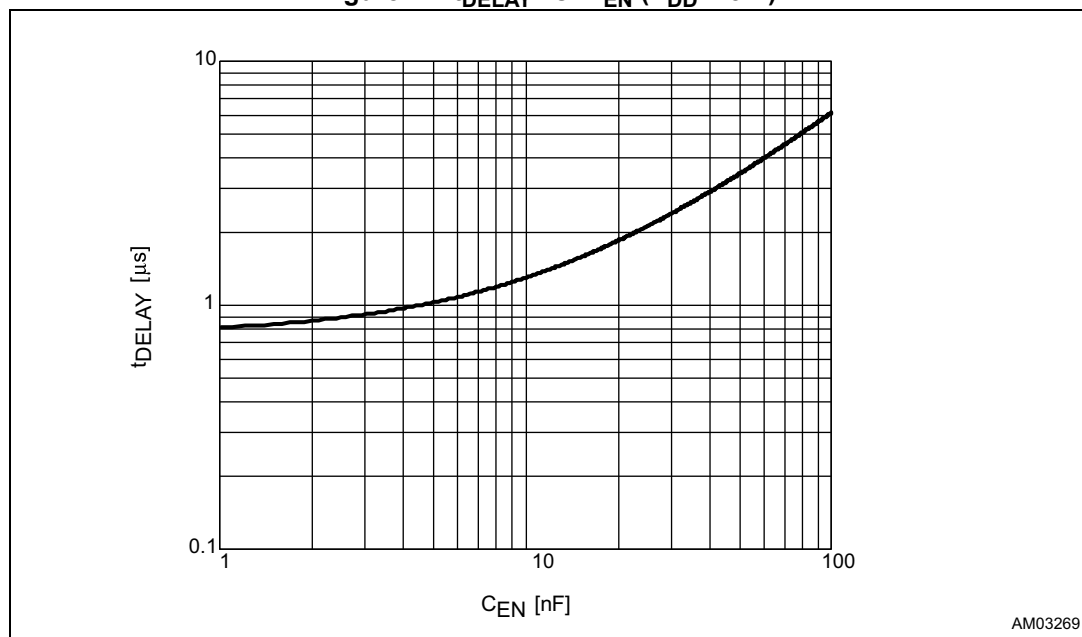


Figure 16.  $t_{\text{DISABLE}}$  vs.  $C_{\text{EN}}$  and  $R_{\text{EN}}$  ( $V_{\text{DD}} = 5 \text{ V}$ )Figure 17.  $t_{\text{DELAY}}$  vs.  $C_{\text{EN}}$  ( $V_{\text{DD}} = 5 \text{ V}$ )

## 5.6 Thermal protection

In addition to the overcurrent detection, the L6207Q device integrates a thermal protection to prevent device destruction in the case of junction overtemperature. It works sensing the die temperature by means of a sensitive element integrated in the die. The device switches off when the junction temperature reaches 165 °C (typ. value) with 15 °C hysteresis (typ. value).

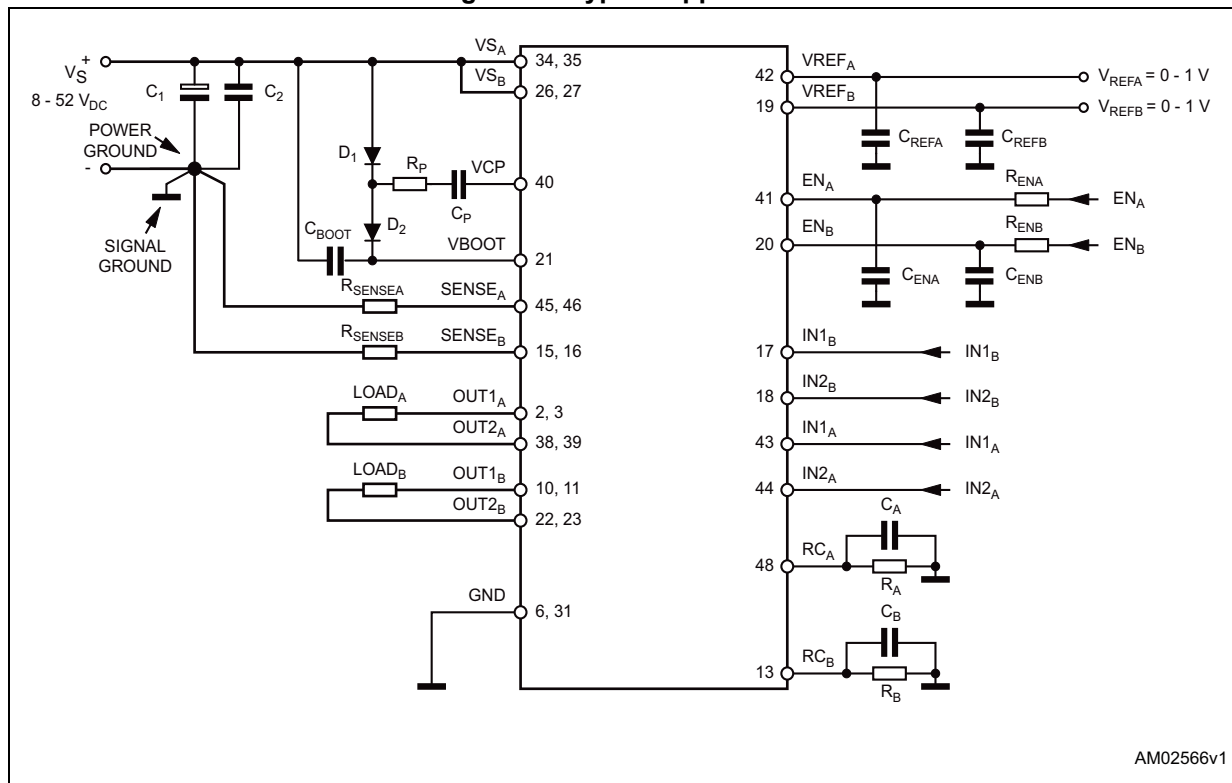
## 6 Application information

A typical application using the L6207Q device is shown in [Figure 18](#). Typical component values for the application are shown in [Table 7](#). A high quality ceramic capacitor in the range of 100 to 200 nF should be placed between the power pins ( $VS_A$  and  $VS_B$ ) and ground near the L6207Q to improve the high frequency filtering on the power supply and reduce high frequency transients generated by the switching. The capacitors connected from the  $EN_A$  and  $EN_B$  inputs to ground set the shutdown time for bridge A and bridge B, respectively, when an overcurrent is detected (see [Section 5.5](#)). The two current sensing inputs ( $SENSE_A$  and  $SENSE_B$ ) should be connected to the sensing resistors with a trace length as short as possible in the layout. The sense resistors should be non-inductive resistors to minimize the  $di/dt$  transients across the resistor. To increase noise immunity, unused logic pins (except  $EN_A$  and  $EN_B$ ) are best connected to 5 V (high logic level) or GND (low logic level) (see [Section 3](#)). It is recommended to keep power ground and signal ground separated on the PCB.

**Table 7. Component values for typical application**

| Component    | Value          |
|--------------|----------------|
| $C_1$        | 100 $\mu$ F    |
| $C_2$        | 100 nF         |
| $C_A$        | 1 nF           |
| $C_B$        | 1 nF           |
| $C_{BOOT}$   | 220 nF         |
| $C_P$        | 10 nF          |
| $C_{ENA}$    | 5.6 nF         |
| $C_{ENB}$    | 5.6 nF         |
| $C_{REFA}$   | 68 nF          |
| $C_{REFB}$   | 68 nF          |
| $D_1$        | 1N4148         |
| $D_2$        | 1N4148         |
| $R_A$        | 39 k $\Omega$  |
| $R_B$        | 39 k $\Omega$  |
| $R_{ENA}$    | 100 k $\Omega$ |
| $R_{ENB}$    | 100 k $\Omega$ |
| $R_P$        | 100 $\Omega$   |
| $R_{SENSEA}$ | 0.3 $\Omega$   |
| $R_{SENSEB}$ | 0.3 $\Omega$   |

Figure 18. Typical application



**Note:** To reduce the IC thermal resistance, therefore improving the dissipation path, the NC pins can be connected to GND.

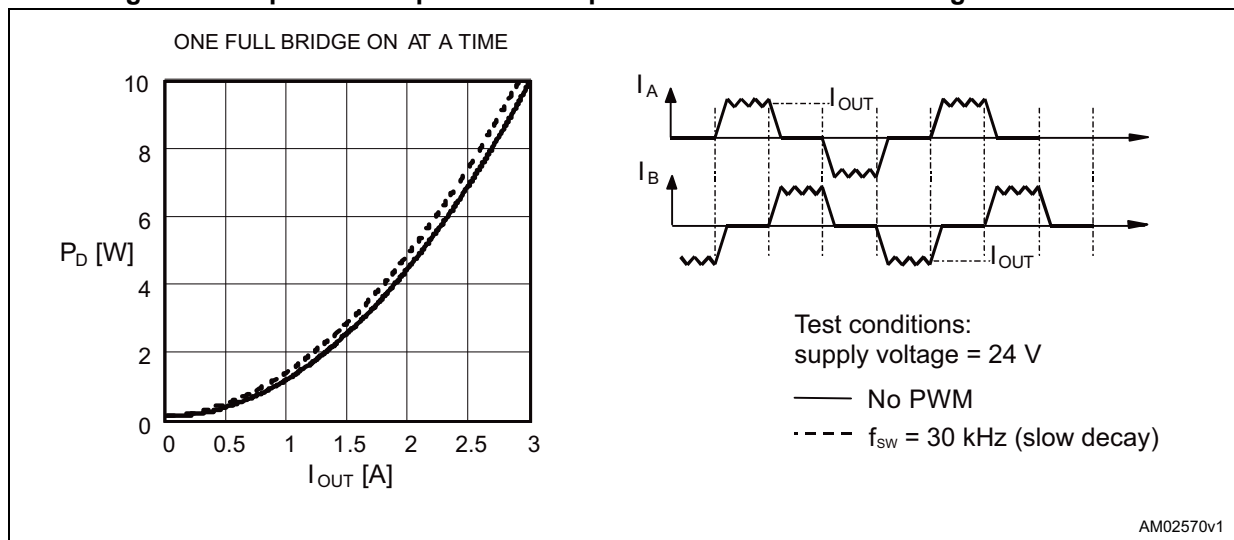
## 7 Output current capability and IC power dissipation

Figure 19 and 20 show the approximate relation between the output current and the IC power dissipation using PWM current control driving two loads, for two different driving types:

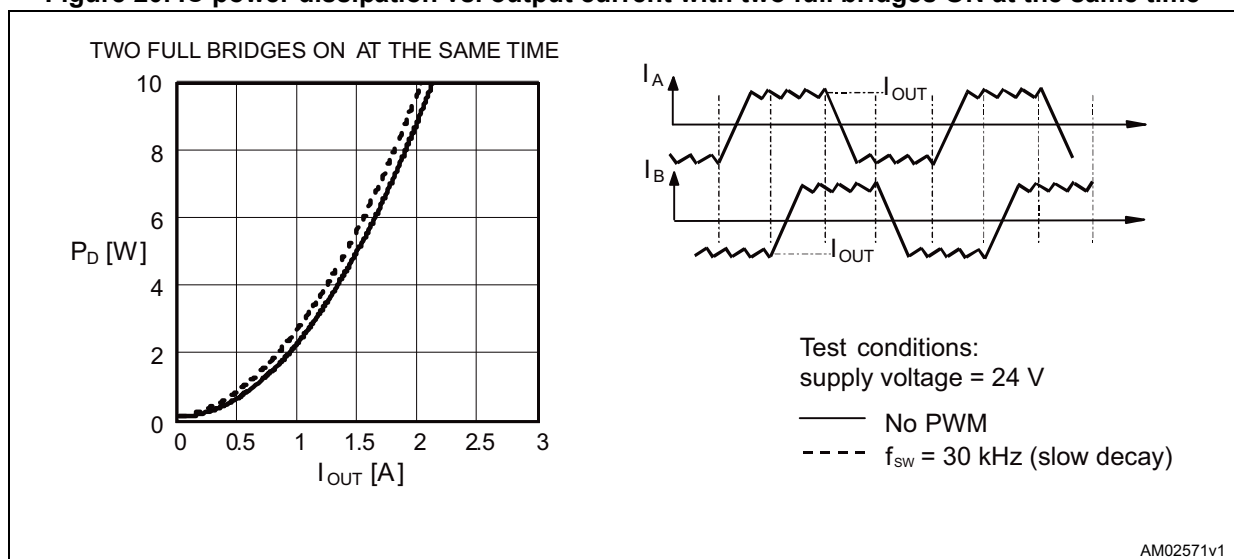
- One full bridge ON at a time (Figure 19) in which only one load at a time is energized.
- Two full bridges ON at the same time (Figure 20) in which two loads are energized at the same time.

For a given output current and driving type the power dissipated by the IC can be easily evaluated, in order to establish which package should be used and how large the onboard copper dissipating area must be to guarantee a safe operating junction temperature (125 °C maximum).

**Figure 19. IC power dissipation vs. output current with one full bridge ON at a time**



**Figure 20. IC power dissipation vs. output current with two full bridges ON at the same time**



## 8 Thermal management

In most applications the power dissipation in the IC is the main factor that sets the maximum current that can be delivered by the device in a safe operating condition. Therefore, it must be considered very carefully. Besides the available space on the PCB, the right package should be chosen considering the power dissipation. Heatsinking can be achieved using copper on the PCB with proper area and thickness.

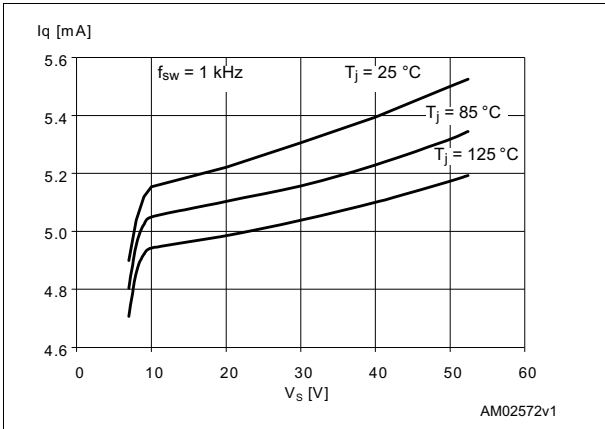
**Table 8. Thermal data**

| Symbol     | Parameter                           | Package                 | Typ. | Unit |
|------------|-------------------------------------|-------------------------|------|------|
| $R_{thJA}$ | Thermal resistance junction-ambient | VFQFPN48 <sup>(1)</sup> | 17   | °C/W |

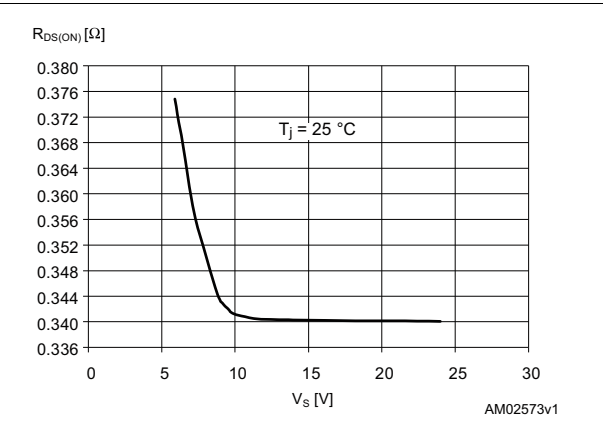
1. VFQFPN48 mounted on EVAL6208Q rev 1 board (see EVAL6208Q databrief): four-layer FR4 PCB with a dissipating copper surface of about 45 cm<sup>2</sup> on each layer and 25 via holes below the IC.

# 9 Electrical characteristics curves

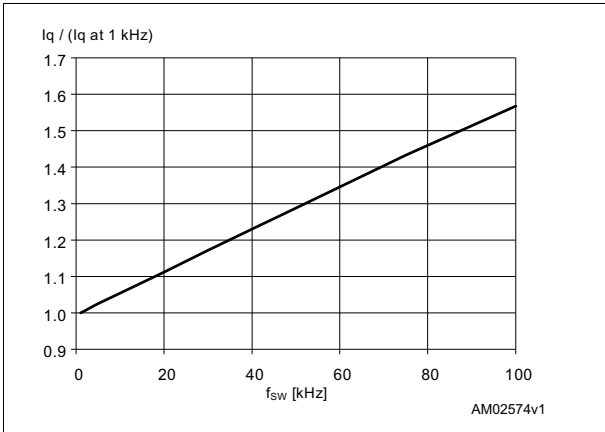
**Figure 21. Typical quiescent current vs. supply voltage**



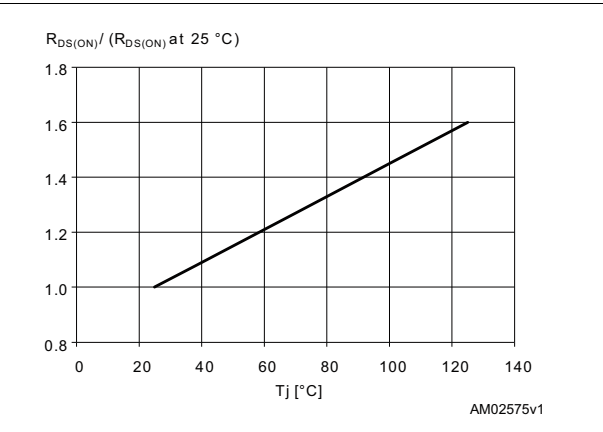
**Figure 22. Typical high-side  $R_{DS(on)}$  vs. supply voltage**



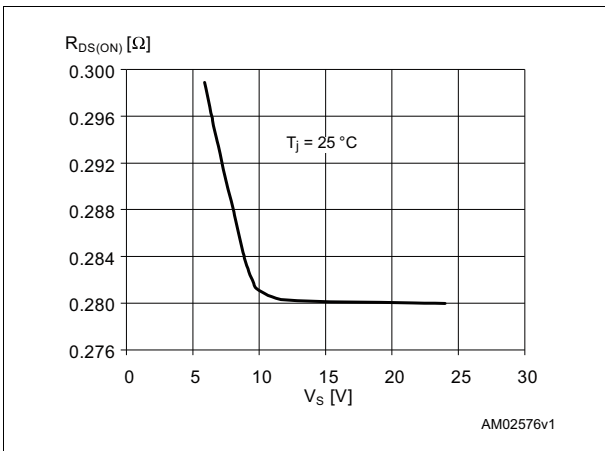
**Figure 23. Normalized typical quiescent current vs. switching frequency**



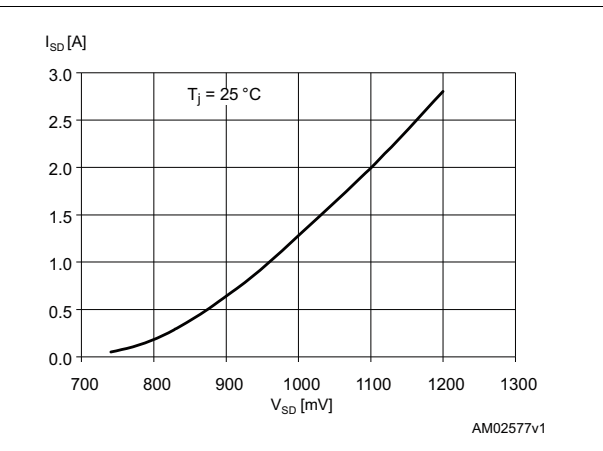
**Figure 24. Normalized  $R_{DS(on)}$  vs. junction temperature (typical value)**



**Figure 25. Typical low-side  $R_{DS(on)}$  vs. supply voltage**



**Figure 26. Typical drain-source diode forward ON characteristic**



## 10 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: [www.st.com](http://www.st.com). ECOPACK is an ST trademark.

**Figure 27. VFQFPN48 (7 x 7 x 1.0 mm) package outline**

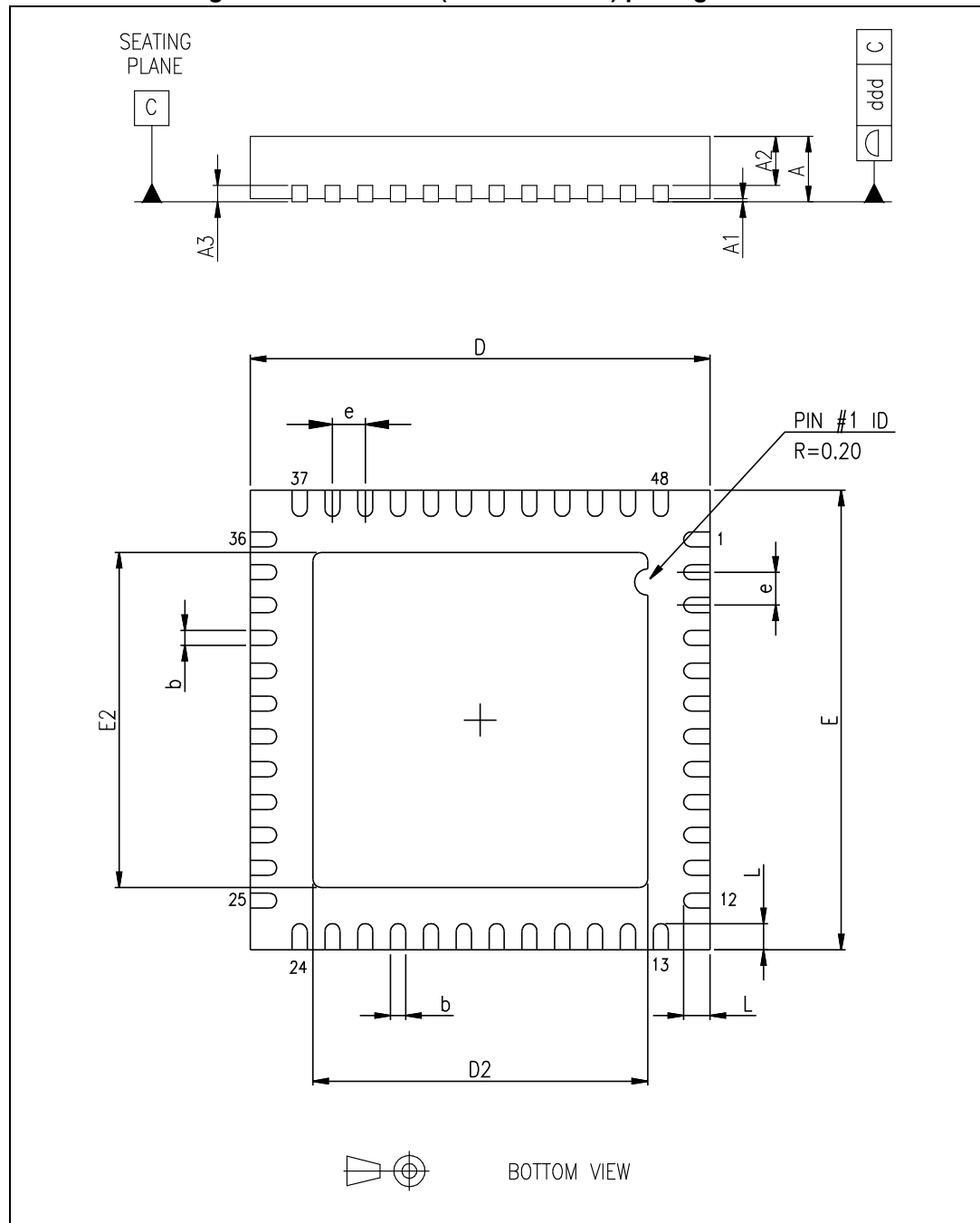




Table 9. VFQFPN48 (7 x 7 x 1.0 mm) package mechanical data

| Symbol | Dimensions (mm) |      |      |
|--------|-----------------|------|------|
|        | Min.            | Typ. | Max. |
| A      | 0.80            | 0.90 | 1.00 |
| A1     |                 | 0.02 | 0.05 |
| A2     |                 | 0.65 | 1.00 |
| A3     |                 | 0.25 |      |
| b      | 0.18            | 0.23 | 0.30 |
| D      | 6.85            | 7.00 | 7.15 |
| D2     | 4.95            | 5.10 | 5.25 |
| E      | 6.85            | 7.00 | 7.15 |
| E2     | 4.95            | 5.10 | 5.25 |
| e      | 0.45            | 0.50 | 0.55 |
| L      | 0.30            | 0.40 | 0.50 |
| ddd    |                 | 0.08 |      |

## 11 Order codes

**Table 10. Ordering information**

| Order codes | Package             | Packaging     |
|-------------|---------------------|---------------|
| L6207Q      | VFQFPN48 7x7x1.0 mm | Tray          |
| L6207QTR    |                     | Tape and reel |

## 12 Revision history

**Table 11. Document revision history**

| Date        | Revision | Changes                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                            |
|-------------|----------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 29-Jul-2011 | 1        | First release                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                      |
| 28-Nov-2011 | 2        | Document moved from preliminary to final datasheet.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                |
| 11-Jun-2013 | 3        | <p>Unified package name to "VFQFPN48" in the whole document.</p> <p><a href="#">Figure 1</a> moved to page 3, added <a href="#">Section 1: Block diagram</a>.</p> <p>Corrected headings in <a href="#">Table 1</a> and <a href="#">Table 2</a> (replaced "Parameter" by "Test condition").</p> <p>Updated note <a href="#">4</a>, below <a href="#">Table 6</a> (replaced "<math>t_{ON}</math>" by "<math>t_{OFF}</math>").</p> <p>Corrected unit in <a href="#">Table 7</a> (row <math>C_1</math>).</p> <p>Added titles to <a href="#">Equation 1</a> to <a href="#">Equation 5</a> in <a href="#">Section 5.3: PWM current control</a>.</p> <p>Added <a href="#">Table 8: Thermal data</a> in <a href="#">Section 8: Thermal management</a>.</p> <p>Updated <a href="#">Section 10: Package information</a> (modified titles, reversed order of <a href="#">Figure 27</a> and <a href="#">Table 9</a>).</p> <p>Unified "<math>C_{EN}</math>", "<math>t_{DT}</math>", "<math>t_{ON}</math>", "<math>t_{OFF}</math>", "<math>C_{OFF}</math>", "<math>R_{OFF}</math>", "<math>V_{th(ON)}</math>", "<math>V_{th(OFF)}</math>" (subscript, lower/upper case) in the whole document.</p> <p>Minor corrections throughout document.</p> |

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